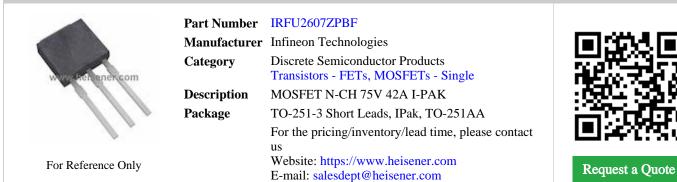


IRFU2607ZPBF

IRFU2607ZPBF Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IRFU2607ZPBF Specifications

Manufacturer Part Number	IRFU2607ZPBF
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-251-3 Short Leads, IPak, TO-251AA
Series	HEXFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	75V
Current - Continuous Drain (Id) @ 25°C	42A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 50µA
Gate Charge (Qg) (Max) @ Vgs	51nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1440pF @ 25V
Vgs (Max)	$\pm 20\mathrm{V}$
FET Feature	-
Power Dissipation (Max)	110W (Tc)
Rds On (Max) @ Id, Vgs	22 mOhm @ 30A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	IPAK (TO-251)
Package / Case	TO-251-3 Short Leads, IPak, TO-251AA
	Report errors?

IRFU2607ZPBF Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IRFU2607ZPBF Payment Methods



IRFU2607ZPBF Shipping Methods



If you have any question about IRFU2607ZPBF, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com